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GAS SENSORS:

PRINCIPLES OF OPERATION AND SENSOR PARAMETERS



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OUTLINE

- Description of Sensors and Transducers
- Classification of Gas Sensors
- Principles of Operations for Gas Sensors
- Sensor Parameters for Solid-State Sensors
- Examples of Chemical Sensors
- Current Aspects on Air Quality Sensors
- Concluding Remarks



WHAT IS A HIGH-PERFORMANCE GAS SENSOR ?





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✓ LOW DETECTION LIMIT

Materials and Transducers for Gas Sensors

	TRANSDUCERS					
	$\Delta c \Rightarrow \Delta \sigma \Rightarrow \Delta i \Rightarrow \Delta v$	Δc == ΔM == Δf	Δc ⇒ ΔM ⇒ Δf	$\Delta c \Rightarrow \Delta 0 \Rightarrow \Delta i \Rightarrow \Delta v$ Semicondia un Gas Sensors SenO ₂ substante: Al ₂ O ₃	$\Delta c \Rightarrow \Delta n \Rightarrow \Delta 1 \Rightarrow$ $\Delta i \Rightarrow \Delta y$ Pher Optic Chemical Sensor $\overline{rrrr} = \frac{1}{2}$	ΔΦ ⇒ Δi ⇒ Δv Schwitz Barrier annor merokrane Semiconcluctor
SENSOR	MOSFET	QCM	SAW	CHEMI-	OPTICAL	SCHOTTKY
MATERIALS		MEMS	TFBAR	RESISTOR		
METAL-OXIDE FILMS						
(SnO ₂ , ZnO, WO ₃ ,)						
CONDUCTING POLYMERS						
THICK FILMS						
RECEPTORS						
ENZYMES						
ANTIBODIES						
ORGANIC FILMS						
DNA						
NANOMATERIALS				CNTs		

Selected Principles of Operation for Gas Sensors

Transducer	Principle of operation	Measurand Input / Signal Output
Conductometric	<i>Electrical Conductivity</i> : Conducting Polymers; Metal Oxides	$\Delta \textbf{c} \rightarrow \Delta \sigma \rightarrow \Delta \textbf{i} \rightarrow \Delta \textbf{V}$
Optical	Absorption; Emission; Fluorescence; Chemiluminescence; Evanescent Wave; Fiber Optics	$\Delta \mathbf{c} \rightarrow \Delta \mathbf{n} \rightarrow \Delta \mathbf{I} \rightarrow \Delta \mathbf{i} \rightarrow \Delta \mathbf{V}$
Electrochemical	<i>Ionic Conductivity</i> : Amperometric; Potentiometric; Voltammetric	$\Delta \textbf{c} \rightarrow \Delta \sigma \rightarrow \Delta \textbf{i} \rightarrow \Delta \textbf{V}$
Thermal	<i>Flow of thermal energy</i> : Catalytic; Pyroelectric; Calorimetric	$\Delta \mathbf{c} \to \Delta \mathbf{T} \to \Delta \mathbf{i} \to \Delta \mathbf{V}$
MOSFET	Charge capacitive coupling	$\Delta \mathbf{c} \rightarrow \Delta \Phi \rightarrow \Delta \mathbf{i} \rightarrow \Delta \mathbf{V}$
Ultrasonic (Mechanical or Acoustic)	<i>Piezoelectricity</i> : QCM; SAW; TFBAR	$\begin{array}{c} \Delta \textbf{c} \rightarrow \Delta \textbf{m} \rightarrow \Delta \textbf{f} \\ \Delta \textbf{c} \rightarrow \Delta \textbf{m} \rightarrow \Delta \textbf{f}, \Delta \phi \end{array}$

 Δc = variation of concentration; $\Delta \sigma$ = variation of electrical conductivity; Δi = variation of current; ΔV = variation of voltage; Δn = variation of refractive index; ΔI = variation of light intensity; ΔT = variation of temperature; $\Delta \Phi$ = variation of work function; Δm = variation of mass; Δf = variation of frequency; $\Delta \phi$ = variation of phase of acoustic wave

GAS SENSORS CLASSIFIED by TRANSDUCERS

Transducer	Principle of operation
Chemoresistor	Electrical Charge Transfer
Electrochemical	<i>Ionic Conductivity</i> : Amperometric; Potentiometric; Voltammetric
Capacitors	Dielectric Constant
Field Effect Transistor	Electrical Charge Channel
Piezoelectric	<i>Mass Loading (Viscoelastic and Acoustoelectric Loading)</i> : QCM; SAW; TFBAR
MEMS	Mass Loading: Micro-Electrical-Mechanical-Systems
Thermal	<i>Flow of thermal energy</i> : Catalytic; Pyroelectric; Calorimetric
Optical	Refractive Index

Type of Sensor: CHEMIRESISTOR (1/6)

Two-Pole Conductometric Thin-Film Gas Sensors

Metal-doped Metal Oxide (MOX) Gas Sensor



Carbon Nanotube (CNT) Gas Sensor





A transfer of **electrical charge** (carrier) occuring between targeted gases (**electro-donating** or **electro-accepting**) with sensitive semiconductor materials of *n-type* (MOX) or *p-type* (CNT).

Class of Sensor Materials	n-type	p-type
Metal Oxides (MOX) (SnO ₂ , ZnO, WO ₃ , TiO ₂ , ZrO ₂ , Al ₂ O ₃ , etc.)	X	
Carbon Nanotubes (CNTs)		X
Conducting Polymers (CP) (Polypyrrole, Polythiophene, Polyacetylene, etc.)		X
Organic Materials	-	-

Type of Sensor: CHEMIRESISTOR (2/6)

Energy bands at the grain boundary for polycrystalline SnO₂



Madou and Morrison equations:

 $\begin{array}{c} \textbf{CO} + \textbf{O}_2^{--} \rightarrow \textbf{CO}_2 + 2\textbf{e}^{-} \\ \textbf{CO} + \textbf{O}^{--} \rightarrow \textbf{CO}_2 + \textbf{e}^{-} \end{array}$

$\mathbf{G} = \mathbf{G}_0 + \mathbf{k} \ (\mathbf{P}_{\mathrm{CO}})^{\mathrm{m}}$

G = Conductance $G_0 = Initial \ Conductance$ k = constant $P_{CO} = CO \ partial \ pressure$ $m \approx 0.5$

Type of Sensor: CHEMIRESISTOR (3/6)

Metal-modifications and catalysts



Co CNTs



CNTs Au-10nm

Au-Clusters Size = 5-60 nm

CNTs Au-5nm Au-Clusters Size = 5-30 nm

Spillover is the mechanism which is related to the presence of catalysts (e.g., noble metals: Pt, Pd, Au, Ag, etc.) onto the semiconductor surface. Supported catalysts (e.g., Pt) dissociate gas molecules (H_2 or O_2) to be detected; the oxygen and hydrogen atoms spill over the semiconducting surface and the reaction rates of the tested gases on the sensor surface are enhanced for improved gas sensitivity and detection limit, at lower sensor operating temperatures (room temperature).

Gold (Au) nanoclusters (size ranging from10 to 50 nm) onto Carbon Nanotube layers for Gas Sensors by ENEA

M. Penza et al., Journal of Sensors, 2008, 107057 M. Penza, et al., Sensors and Actuators B, 140(1) (2009) 176-184

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Type of Sensor: CHEMIRESISTOR (4/6)

Electrical Behaviour of Chemoresistors



Gas Sensors by ENEA

Class of Target Gas	n-type Material	p-type Material
Electron-donating Gases (Reducing Gases):	Resistance	Resistance
CO, NH ₃ , H ₂ , H ₂ S, SO ₂ , CH ₄ , CO ₂ , etc.	DECREASE	INCREASE
Electron-accepting Gases (Oxidising Gases):	Resistance	Resistance
$NO_2, O_2, O_3, etc.$	INCREASE	DECREASE



Reducing gases induce an increase in the electrical resistance of CNTs sensors (p-type)

Electron charge transfer generates **conductivity change in the gas sensors:**



Oxidizing gases induce a decrease in the electrical resistance of CNTs sensors (p-type)

Type of Sensor: CHEMIRESISTOR (5/6)

MODEL OF *p-type* CHARGE TRANSFER IN THE SEMICONDUCTING FUNCTIONALIZED CARBON NANOTUBES FILMS GAS SENSORS

UNMODIFIED CNTs: MODEL OF DIRECT INJECTION OF ELECTRICAL CHARGE

Electron-acceptor gases (NO2, O2)

Electron-donating gases (NH₃, H₂S, CO)



Type of Sensor: CHEMIRESISTOR (6/6)

Some Gas Responses of a Chemoresistor



Gas Sensors by ENEA

-CNT - CNT:Pt ---- CNT:Ag -CNT:Ru 152°C (e) (a Resistance change (Ω) $a = 1\% H_{,;}$ $b = 0.7\% CH_{1}$ c = 0.2% CO₂; d = 0.1% CO e = 0.1% NH; f = 10 ppm NO, -3 400 100 200 300 500 Time (min)

NO₂ oxidizing gas induces a <u>decrease</u> in the electrical resistance of CNTs sensors (p-type)

Reducing gases (CO, NH₃, H₂, CH₄, CO₂) induce an <u>increase</u> in the electrical resistance of CNTs sensors (p-type)

M. Penza et al., Nanotechnology, 21 (2010) 105501

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Type of Sensor: ELECTROCHEMICAL

Electrical charge exchange between gas and ionic conductor



Electrochemical gas sensors are cells whose output electrical signal is directly related to the concentration or partial pressure of the gaseous species. Depending on whether the output signal is an electromotive force or a current, the device may be classified in *potentiometric* or *amperometric* electrochemical sensors.

B4 family sensors: NO₂ test up to 200 ppb in Alphasense Lab



Type of Sensor: CAPACITORS & CHEMIRESISTORS

The capacitance between two parallel electrodes in the Capacitor is modulated by the dielectric constant of a sensing material under gas exposure.



Type of Sensor: FIELD EFFECT TRANSISTORS

The current between Source (S) and Drain (D) in the Fielf Effect Transistor (FET) is modulated by the voltage of a back Gate (G) under gas exposure.



D. R. Kauffman et al., Angew. Chem. Int. Ed., 47 (2008) 6550-6570

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Figure 5. Drain currents for $V_{sd} = -100 \text{ mV}$ and $V_g = -20 V$ are shown as a function of time for application of saturated vapor of various kinds of alcohols: methanol, ethanol, 1-propanol, 2-propanol, 1-butanol, tertiary-butanol, 1-pentanol, and 1-octanol.

T. Someya et al., NANOLETTERS, 3-7 (2003) 877-881

Type of Sensor: PIEZOELECTRIC (1/6) *MASS-SENSITIVE ACOUSTIC WAVE DEVICES*



OUTPUT FREQUENCY





- **BAW** (Bulk Acoustic Wave) <u>QCM</u> (Quartz Crystal Microbalance) at a resonating frequency ranging from 5 to 30 MHz.
- <u>SAW</u> (Surface Acoustic Wave) at a high resonating frequency ranging from 50 MHz to 1 GHz.
- **TFBAR** (Thin Film Bulk Acoustic Resonator) at a resonating frequency ranging from 1 to 10 GHz.

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Type of Sensor: PIEZOELECTRIC (2/6) QCM - QUARTZ CRYSTAL MICROBALANCE

SENSING MECHANISM: MASS LOADING OF QCM RESONATOR SENSOR

The resonating frequency of a piezoelectric material (e.g., AT-cut quartz), configured as oscillator, is modulated by the adsorbed mass of gas molecules in active material



OUTPUT FREQUENCY

Acoustic device type	Mass sensitivity (cm²/g)	Frequency range
QCM	10 – 20	5 – 30 MHz
SAW	200 – 400	50 – 1000 MHz

$$S_m = \lim_{\Delta m \to 0} \frac{(\Delta f / f)}{(\Delta m / A)}$$

$$S_m = mass sensitivity$$

 $\Delta m = mass change$
 $\Delta f = frequency change$
 $f = resonant frequency$
 $A = sensing area$



Sauerbrey equation (1959):

$$\Delta f = S_m f_o^2 \frac{\Delta m}{A}$$

Type of Sensor: PIEZOELECTRIC (3/6) QCM - QUARTZ CRYSTAL MICROBALANCE OSCILLATORS FOR QCM RESONATOR SENSORS



Colpitts Oscillator







Response of a 10 MHz QCM sensor coated with layer of Single-Walled Carbon Nanotubes exposed towards Xylene vapors, at room temperature

M. Consales et al., IEEE Trans NANO, 6-6 (2007) 601-612

Type of Sensor: PIEZOELECTRIC (4/6) SAW - SURFACE ACOUSTIC WAVES



$$\Delta f = -c_m f_o^2 \Delta \rho_s + c_e f_o^2 \Delta [hG'] - \frac{K_t^2}{2} \Delta \left[\frac{\sigma_s^2}{\sigma_s^2 + v_o^2 C_o^2} \right]$$

SAW





Piezoelectric film



 $\Delta f_V = \Delta f_M C_V \frac{K}{\rho_S}$

$$K = \frac{C_S}{C_V}$$

ML = Mass Loading VL = Viscoelastic Loading AL = Acoustoelectric Loading

M. Penza et al., IEEE Trans UFFC, 45-5 (1998) 1125-1132

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(AL)

 $\Delta f =$ frequency shift $c_m =$ mass sensitivity coefficient f_a = fundamental SAW resonant frequency Δm = mass change at the surface of membrane A = area of the SAW sensing membrane $\rho_{\rm s}$ = density of the sorbent phase of the analyte G' = real part of the shear modulus, G = electromechanical coupling coefficient v_a = unperturbed velocity of the SAW σ_s = sheet conductivity of the sensing film C_0 = capacitance per unit length of SAW substrate $C_0 = \varepsilon_s + \varepsilon_0$ ε_{s} = permettivity of substrate ε_0 = permettivity of free space K =partition coefficient $C_{\rm s}$ = concentration of vapor in the sorbent phase C_{ν} = concentration of vapor in the vapor phase $\Delta f_{\rm W}$ = frequency shift due to mass loading Δf_{M} = frequency shift caused by sorbent phase

Type of Sensor: PIEZOELECTRIC (5/6) SAW - SURFACE ACOUSTIC WAVES



Ethanol concentration (ppm)

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Type of Sensor: PIEZOELECTRIC (6/6) TFBAR - THIN FILM BULK ACOUSTIC RESONATORS







TFBAR

TFBAR SENSOR AS PASSIVE DEVICE MEASURED BY NETWORK ANALYZER

Thickness of 75wt.% SWCNTs-CdA LB Film = 28 nm Cadmium arachidate (CdA) is Host-matrix SWCNTs are fillers of NANOCOMPOSITE

M. Penza et al., IEEE Trans. Electr. Dev. 55-5 (2008) 1237

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Acoustic device type	Mass sensitivity (cm²/g)	Frequency range
QCM	10 – 20	5 – 30 MHz
SAW	200 – 400	50 – 1000 MHz
TFBAR	500 – 1000	1 – 20 GHz



Type of Sensor: MEMS - MICRO ELECTRICAL MECHANICAL SYSTEMS

Towards a miniaturized MEMS e-nose

Frequency change induced by adsorbed mass onto individual cantilever





Courtesy by Sywert H. Brongersma from IMEC Holst-Centre

Type of Sensor: PYROELECTRIC or CATALYTIC

Outline of the pellistor heated-catalyst sensor

Wheatstone bridge for catalytic sensor



The pellistor is heated to about 500°C by passing electrical current through the Pt resistance wire. Any increase in temperature resulting from **oxidation** of a gas to be detected on the Pt-doped surface of the bead causes a resistance change, which is measured by means of a Wheatstone bridge circuit.

E. Allan Symons, Catalytic Gas Sensors, in Gas Sensors, G. Sberveglieri Ed., 1992 Kluwer Academic Publishers



Type of Sensor: OPTICAL FIBER

Optical Fiber Gas Sensors





Refractometry

M. Consales, UNISANNIO (Italy)

M. Giordano, CNR-IMCB, (Italy)



overall diameter: 125 μm core diameter: 6 μm



The sensor is based on the **Fresnel reflection** principle: the **reflection coefficient R** is related to the difference between the medium *refractive index* n_m , the fiber optic *refractive index* n_f and the *incidence angle*. In the case of a monomode fiber, the reflection coefficient **R** at the end of the **interface fiber-layer** can be expressed as above equation.

GAS SENSORS: SENSOR PARAMETERS



SENSOR PARAMETERS

Sensor Parameter	Figure of Merit			
Response	Δ R (Ohm); Δ R/R (%); R _i / R _f ; Δ V (V); Δ I (A); V _i / V _f ; I _f / I _i ; Δ C (F); Δ f (Hz)			
Sensitivity	Δ R/c (Ohm/ppm); (Δ R/R)/c (%/ppm); Δ f/c (Hz/ppm); etc.			
Response Time	t _R (sec or min)			
Recovery Time	t _c (sec or min)			
Limit of Detection	LOD (ppm or ppb)			
Selectivity	Zero cross-sensitivity (<i>ideal case</i> !)			
Reproducibility	Dispersion (%) of results in measurements under specific conditions			
Repeatability	Dispersion (%) of results in repeated measurements			
Stability & Drift	Attitude (% of full scale) to keep constant in time a metrological feature			
Accuracy	Attitude (% dispersion) to give a result close to true value of a measurand			
Resolution & Noise	Minimum <i>resolved</i> value of a measurand compared to a defined level of noise			
R = Electrical Resistance; I = Current; V = Voltage; C = Capacitance; f = Frequency; t = time; c = gas concentration; ppm = part per million; ppb = part per billion				

Sensor Parameter: RESPONSE

SENSOR RESPONSE: The output signal of the sensor stimulated by an external perturbation (e.g., gas concentration). The <u>Calibration Curve</u> is defined as the functional relationship of the sensor response versus gas concentration.



<u>ATTENTION LEVEL</u> = 100 ppb NO₂ - <u>ALARM LEVEL</u> = 200 ppb NO₂ (Italian Regulations D.M. 15 April 1994 & Daughters)

Sensor Parameter: SENSITIVITY (1/2)

SENSITIVITY: In metrology and analytical chemistry, the sensitivity (S) is defined as the slope of the calibration curve. In other terms, the sensitivity is the response change of a sensor divided by the related variation of the input gas concentration.

Sensor Sensitivity for Linear Calibration Curves: Examples: %/ppm; mV/ppm;

Hz/ppm; mA/ppb

 $S = \frac{\Delta V}{\Delta m}$ V_{out} V_{1} M_{1} M_{1} M_{2} M_{2} M_{3} M_{4} M_{5} M_{5}

Sensor Sensitivity for <u>Not-Linear Calibration Curves</u>: Examples: Ohm/ppm; mV/ppb; Hz/ppm; μF/ppb



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Sensor Parameter: SENSITIVITY (2/2)

SENSITIVITY: In metrology and analytical chemistry, the sensitivity (S) is defined as the slope of the calibration curve. In other terms, the sensitivity is the response change of a sensor divided by the related variation of the input gas concentration.

> Other Figure of Merit: Mean Sensitivity

$$S_m = \frac{1}{n} \sum_{i=1}^n \frac{(\Delta R / R)_i}{c_i} (\% / ppm)$$

 S_m =average sensitivity

 $\Delta R / R_i =$ sensor response

 $c_i = gas \ concentration$

n = number of exposures

M. Penza, et al., Sensors and Actuators B, 140(1) (2009) 176-184.

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Sensor Parameter: RESPONSE TIME & RECOVERY TIME

<u>RESPONSE TIME</u>: the time interval (RISE TIME) that the output response of a sensor goes through from 10 % to 90% of the final steady-state value upon reached stationary conditions.

<u>RECOVERY TIME</u>: the time interval (FALL TIME) that the output response of a sensor goes through from 90 % to 10% of the final steady-state value upon reached stationary conditions.



Good Response Time: < 10 sec Good Recovery Time: < 60 sec

Sensor Parameter: LIMIT OF DETECTION (LOD)

LIMIT OF DETECTION: In metrology and analytical chemistry, the limit of detection (LOD) is defined as the minimum gas concentration (measurand) detected by a sensor (instrument) with a related output signal referenced to a fixed level of noise. The LOD is calculated as the *Minimum Detectable Value* (MDV) measured by a sensor, increased by *at least 3 times* (IUPAC requirement) related to measured *Noise* (N) level to be accurate, divided by *Sensitivity* (S) (slope of linear calibration curve).

$$LOD(ppm) = 3MDV/S$$

EXAMPLE of LOD Calculation for a Chemoresistor:

Noise = 10 Ohm; S/N = 3; MDV of a chemoresistor = 30 Ohm; S = 120 Ohm/ppm LOD (ppm) = 3MDV /S = 30 Ohm / 120 Ohm/ppm = 0.25 ppm = 250 ppb

Sensor Parameter: SELECTIVITY

SELECTIVITY: degree of specificity of the response of a sensor to a given gas (target measurand) with *negligible cross-sensitivity* towards other interfering gases.

Usually, the gas sensitivity (S) of a sensor can be defined as a vector (V) with multiple components (V_i) depending on various tested gases (x_i) (*real case*):

$$dV_o = \frac{\partial V_o}{\partial x_i} dx_1 + \ldots + \frac{\partial V_o}{\partial x_n} dx_n = \sum_i \frac{\partial V_o}{\partial x_i} dx_i = \sum_i S_i dx_i$$

If the sensitivity towards a single given component (target gas) is dominant, then the sensor can be considered selective or specific (*ideal case*).



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Sensor Parameter: REPRODUCIBILITY

REPRODUCIBILITY: degree of agreement among results of successive measurements of the same measurand when individual measurements are performed changing the following conditions: method of measurement; instrument; usage conditions (temperature, pressure, etc.); time of measurement; operator; place of measurement; frequency of measurements.

REPRODUCIBILITY can be expressed by a <u>Standard Deviation</u> (**o**) as a Dispersion (%) of the results in the reproduced measurements.

$$\sigma = \sqrt{\frac{1}{n-1} \sum_{i=1}^{n} (x_i - \overline{x})^2}$$

Good Reproducibility: σ < 10%

- x represents the result of the i-th measurement
- \overline{x} represents the arithmetic average of n measurements

A. D'Amico and C. Di Natale, IEEE Sensors Journal, Vol. 1, N. 3, October 2001, pp. 183-190

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Sensor Parameter: REPEATABILITY

REPEATABILITY: degree of agreement among results of successive measurements of the same measurand under specific conditions: same method of measurement; same instrument; same usage conditions (temperature, pressure, etc.); time of measurement; same operator (observer); same place of measurement; frequency of measurements.

REPEATABILITY can be expressed by a <u>Standard Deviation</u> (**o**) as a Dispersion (%) of the results in the repeated measurements.



D = Coefficient of Variation (%)

SD = Standard Deviation; M = Mean

1	The LOWER D, the BETTER REPEATABILITY					
		SENSOR CNTs_Au-10nm				
	GAS CONC.	200 ppb NO ₂	1 ppm NO ₂	10 ppm NO ₂		
D	$\mathbf{P} = (SD/M)$	<mark>)%</mark> 12.1 %	3.08 %	1.50 %		

M. Penza et al., Sens. and Actuators B 140. 2009, 176-184

Sensor Parameter: STABILITY & DRIFT

STABILITY: Attitude of a sensor to maintan constant in the time its metrological characteristics (i.e., gas response), or as a function of other foreign parameters as external perturbations. It can be expressed as data dispersion (%) related to full scale.

<u>DRIFT</u>: Slow time variation of a metrological feature (i.e., baseline) with unpredictable statistics. Instabilities of sensing material (*ageing effects*) and ambient interactions (*temperature, humidity*) are the main causes of changes of the overall performance (i.e., sensor response) in the device.



Drift of the Baseline of the Au-modified CNT sensor in the period of ca. 3 hours

NO₂ detection at gas concentration ppb level

M. Penza et al., Journal of Sensors, Vol. 2008, ID107057.

Sensor Parameter: ACCURACY

ACCURACY: Attitude of a sensor (instrument) to give an indication close to the true value of the measurand under test. The concept is clarified as follows:



A. D'Amico, C. Di Natale, A. Taroni, Sensors Parameters, in Proceedings of the 1st European School on Sensors (ESS'94).

Sensor Parameter: RESOLUTION & NOISE

RESOLUTION & NOISE: RESOLUTION is usually defined as the minimum meaningful value of a measurand that a sensor is able to detect. Resolution, in principle, is limited by the NOISE occurring both on the sensor (active material) and electronics (amplifier) used to readout the sensor response.

Type of noise	Current Spectral Density Si(f)
Thermal (Johnson)	4kTG
Generation - Recombination Burst	$A_I \frac{\tau^2}{l+4\pi^2 \tau^2 f^2}$
Shot	2ei
Flicker	$A_2 \frac{\overline{i}^{\gamma}}{f^{\alpha}}$

Most common kinds of Noise sources

A. D'Amico, C. Di Natale, A. Taroni, Sensors Parameters, in Proceedings of the 1st European School on Sensors (ESS'94).

Roadmap of the R&D on Solid-State Gas Sensors				
Year	Type of Sensor	Investigator(s)	Comments/References	
1953	Surface modifications of a semiconductor by a cycle wet/dry of a gas	W. Brattain, J. Bardeen	Bell. Syst. Tech. J., 32 (1953) 1	
1962	Thin film gas sensor based on semiconducting metal oxides	T. Seyama	Analytical Chemistry 34 (1962) 1502	
1962	Gas sensor based on semiconducting oxide	N. Taguchi	Jpn. Patent 45-38200, 1962	
1964	Quartz piezoelectric sensor for gas/vapor detection	W. H. King	Analytical Chemistry 36 (1964) 1735	
1967	Glucose sensor	S.J. Updike et al.	Nature 214 (1967) 986	
1970	Gas sensor based on semiconducting oxide (SnO ₂)	K. Taguchi	US-Patent 3631436 (1970)	
1970	Sensor based on Ion-Sensitive Field Effect Transistor (ISFET)	P. Bergveld	IEEE Trans. Biomed. Eng. BM-17 (1970) 70	
1975	Gas sensor based on semiconducting polymers	J. Janata <i>et al.</i>	Analytical Chemistry 47 (1975) 2238	
1975	Sensor MOSFET with Palladium gate for detection of hydrogen	I. Lundstrom et al.	Appl. Phys. Lett. 26 (1975) 55	
1978	Gas Sensor based on p-type semiconductor	J. R. Stetter	J. Colloidal Interfaces Science 65 (1978) 432	
1979	Study of sensing mechanisms of semiconducting gas sensors	N. Yamazoe et al.	Surface Science 86 (1979) 335	
1980	Gas Sensor based on optical fiber coated by senstive dye	J. I. Peterson <i>et al.</i>	Science 224 (1980) 123	
1982	SAW quartz sensor coated with Palladium film for hydrogen detection	A. D'Amico et al.	Appl. Phys. Lett. 41 (1982) 300	
1984	SAW gas and vapour sensor based on gravimetry	H. Wohltjen	Sensors and Actuators 5 (1984) 307	
1985	Study of sensing mechanisms at surface and bulk of semiconductors	W. Gopel	Surface Science 20 (1985) 9	
1987	SAW sensor at high frequency with polymers coatings for vapor/gas sensing	R. M. White et al.	IEEE Tr. Ultr. Ferr. Freq. Contr. 34 (1987) 162	
1991	Discovery of Carbon Nanotubes	S. lijima	Nature 354 (1991) 56	
1991	Multisensor system for detection of vapors and odours by pattern recognition	J. W. Gardner	Sensors and Actuators B 4 (1991) 109	
1992	Gas sensor based on SnO_2 semiconducting thin-film prepared by RGTO	G. Sberveglieri	Sensors and Actuators B 6 (1992) 239	
1995	Electronic Nose based on thin-film sensors for wine aroma profile	C. Di Natale et al.	8° Conference EUROSENSORS, Stockolm	
1996	Electronic Nose based on polymeric film sensors for chemical detection	K. C. Persaud et al.	Handbook Biosensors and Electronic Noses	
2000	Sensor based on carbon nanotubes for detection of NO_2 and NH_3	H. Dai <i>et al</i>	Science 287 (2000) 622	
2001	Nanosensor based on Silicon nanowire for detection of chemical and biological species	C.M. Lieber et al.	Science 293 (2001) 1289	
2002	Gas sensor based on a SnO_2 semiconducting nanobelt	G. Sberveglieri et al.	Appl. Phys. Lett. 81 (2002) 1869	
2003	Gas sensor based on carbon nanotubes for gas and vapour detection	M. Meyyappan <i>et al.</i>	Nano Letters 3 (2003) 929	
2005	Bio-sensors based on carbon nanotubes for biomedical applications	J. TW. Yeow et al.	IEEE Trans. NanoBioscience 4 (2005) 180	
2007	Development of monocrystalline nanowires for functional applications	C.M. Lieber e Z.L. Wang	MRS Bullettin 32(2) (2007) 99	
2009	Nanoelectronic Nose based on CNT sensor array for gas discrimination	C. Zhou et al.	Nanotechnology 20 (2009) 125503	
2010	Detection of individual gas molecules adsorbed on graphene	K. Novoselov, A. Geim Nobel Prize in Physics	Nature Materials 6 (2007) 652-655	

History and Roadmap of Carbon Nanotubes Gas Sensors

YEAR - AUTHOR	TYPE OF SENSOR AND COMMENTS	REFERENCES
1991 - <mark>S. lijima</mark>	Multiwalled Carbon Nanotubes were discovered	Nature 354 (1991) 56
1993 - S. lijima	Singlewalled Carbon Nanotubes were engineered	Nature 363 (1993) 603
2000 - H. Dai	First SWCNT gas sensor for NO $_2$ and NH $_3$ gas detection	Science 287 (2000) 622
2000 - P.G. Collins	SWCNT gas sensor for O_2 gas detection	Science 287 (2000) 1801
2001 - H. Dai	Functionalized CNT gas sensor for H ₂ gas detection	Adv Mater 13 (2001) 1384
2003 - L. Valentini	CNT-based Chemiresistor for NO ₂ gas detection at 165°C	Appl. Phys. Lett. 82 (2003) 961
2003 - T. Someya	SWCNT-based FET for vapour detection	Nano Lett. 3 (2003) 877
2003 - M.Meyyappan	CNT gas sensor for vapor/gas detection at room temperature	Nano Lett. 3 (2003) 929
2005 - J. Yeow	Review on CNT Biosensors for mediacal applications	IEEE Trans. NanoBiosci. 4 (2005) 180
2007 - CM Lieber and ZL Wang	Singlecrystalline Nanowires for functional applications	MRS Bulletin 32 (2007) 99
2007 - M. Penza	Effect of growth-catalysts on sensitivity of CNT gas sensors	Appl. Phys. Lett. 90 (2007) 103101
2008 - E. Llobet	Carbon nanotube-TiO ₂ hybrid films for detecting O ₂ traces	Nanotechnology 19 (2008) 375501
2009 - C. Zhou	Electronic Nose CNT sensor-array for gas discrimination	Nanotechnology 20 (2009) 125503
2010 - K. Novoselov, A. Geim Nobel Prize in Physics	Detection of individual gas molecules adsorbed on graphene	Nature Materials 6 (2007) 652-655

Selected Examples of Gas Sensors and Sensor Systems



Metal oxide (SnO₂) **Carbon Nanotubes** Nanowires nets by Univ. of Brescia by Ames NASA





GasFET by EPFL, CH







Carbon Nanotube Gas Sensors



Autonomous Gas Sensor System by IREC and Univ. of Barcelona

Lisbon

13-14 November 2009

Sensor units components



UNITEC srl, ETL3000 multi-component outdoor air quality monitor

AEROQUAL, AQM 60 Air Quality Sensors Station



An Octocopter, the first platform on which we (Max Planck Institute for Biogeochemistry, Jena, Germany) tested a measurement sensor package for air quality sensors.

Cantilever Sensor by DTU, DK



SenseAir SA. A Robust Low-Cost NDIR Sensor Platform for sub-ppm Gas Detection



400 gm (incl. batteries) UNIVERSITY OF CAMBRIDGE





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Fixed measurements: definition

'fixed measurements' means measurements taken at fixed sites to determine the levels in accordance with the relevant *Data Quality Objectives* (DQO);

Fixed measurements are mandatory in zones and agglomerations where the upper assessment thresholds are exceeded.

AQD: European DIRECTIVE 2008/50/EC on ambient air quality and cleaner air for Europe, art. 2



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AQD: Data Quality Objectives (DQO)

	SO ₂ , NO ₂ /NOx , CO	Benzene	O ₃
Uncertainty for fixed measurements	15 %	25 %	15 %
	Fluoresc., chemil., NDIR	automatic GC or pumped sampling	UV photometry
	demonstration of equivalence would be mandatory to use micro-sensors		



Indicative methods: definition

'indicative measurements' means measurements which meet data quality objectives that are less strict than those required for fixed measurements;

AQD: European Directive 2008/50/EC on ambient air quality and cleaner air for Europe, art. 2

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AQD: Data Quality Objectives (DQO)

	SO ₂ , NO ₂ /NO /NOx, CO	Benzene	O ₃
Uncertainty for fixed measurements	15 %	25 %	15 %
Uncertainty for indicative measurements	25 %	30 %	30 %
	diffusive samplers, <i>micro-sensors</i>		



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FUTURE RESEARCH TRENDS in AQ SENSORS New Sensor Technologies

- Miniaturisation of MOX: huge number of publications on nano particles, nano-wire, carbon nanotubes: <u>no commercial sensors yet</u>
- Graphene sensors (material with low resistance able to enhance sensitivity) no commercial sensors yet
- Chemical filter directly coated on the sensing layer to avoid crosssensitivity (NO₂ and O₃)
- Low-cost and Low-power Gas Sensors (Alphasense Ltd, SenseAir SA, UST GmbH, SGX-Sensortech SA, Sensichips srl, Figaro Inc, FIS Inc, etc.) in integrated air-quality stations (Unitec, Aeroqual, Contec, Libelium, Environnement, etc.), personal light badge



FUTURE TRENDS in AIR QUALITY SENSORS European Policy for the use of sensors

Micro-sensors:

- for now: not mentioned, not foreseen in European legislation for regulatory purposes
- European Members States shall demonstrate that the Data Quality Objective for Indicative Methods is met (*national projects*).
- For now, the European Commission mainly observes the results of some Research projects related to micro-sensors: *MACPoll*, *AIRMONTEC*, *FP7- ENV.2012.6.5-1* (air quality monitoring in a "Smart City" context with community involvement, S3-EURUSSIA, *COST Action TD1105 EuNetAir*, etc. ...)



CONCLUSIONS

- Nanomaterials for AQC sensors
- Low-cost Gas Sensors
- Low-power Sensor-Systems
- Wireless Technology (Environmental Sensors Network)
- Air Quality Modelling
- Environmental Measurements
- Standards and Protocols
- Guidelines for Best Coupling Gas/Transducer
- Personal Exposure and Health Assessment















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- M. Gerboles, EC JRC-Ispra, Invited Talk at COST Action TD1105 Rome meeting, 4-6 Dec. 2012.



European Network on New Sensing Technologies for Air-Pollution Control and Environmental Sustainability - EuNetAir





Barcelona, 13 - 15 June 2013

UNIVERSITAT de BARCELONA (UB), MIND-IN2UB - Departament d'Electrónica c/ Martí i Franquês, 1 - E-08028 Barcelona, Spain and CSIC-IDAEA, c/ Jordi Girona, 18 - E-08034 Barcelona, Spain









http://ec.europa.eu/environment/greenweek/



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• <u>PON1 BAITAH</u> - Methodology and Instruments **TENTION** of Building Automation and Information Technology for permative models of treatment and the for domestic Healthcare

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